

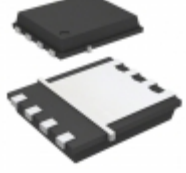
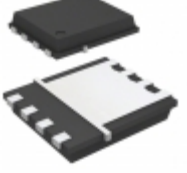
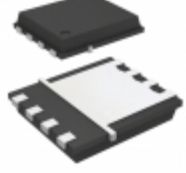
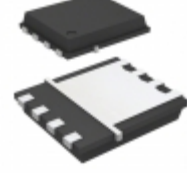

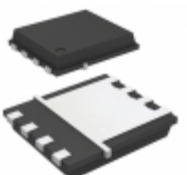
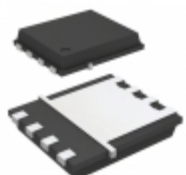
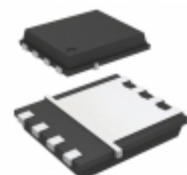
	<h2 style="color: red;">FDMS8560S</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">FDMS8560S</a></p> <hr/> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <hr/> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 25V 30A 8-PQFN</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">FDMS8560S.pdf</a></p> <hr/> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, 27246 pcs Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FDMS8560S
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 25V 30A 8-PQFN
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	27246 pcs Stock
Serie	PowerTrench®, SyncFET™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	8-PQFN (5x6), Power56
Verlustleistung (max)	2.5W (Ta), 65W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	25V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	30A (Ta), 70A (Tc)
Rds On (Max) @ Id, Vgs	1.8 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2.2V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	68nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	4350pF @ 13V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)






FDMS8560S ist neu im Original, Suche FDMS8560S Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDMS8560S Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FDMS8560S: Info@Y-IC.com

Sie können auch interessiert sein:

 <b>FDMS8570S</b> Fairchild/ON Semiconductor MOSFET N-CH 25V 24A 8-PQFN	 <b>FDMS8558SDC</b> FDK America MOSFET N-CH 25V 33A 8-PQFN	 <b>FDMS8558S</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 33A 8-PQFN	 <b>FDMS8570S</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 24A 8-PQFN
 <b>FDMS8460S</b> FAIRCHILD FDMS8460S FAIRCHILD	 <b>FDMS8558S</b> Fairchild/ON Semiconductor MOSFET N-CH 25V 33A 8-PQFN	 <b>FDMS8558SDC</b> Fairchild/ON Semiconductor MOSFET N-CH 25V 33A 8-PQFN	 <b>FDMS8570SDC</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 28A PQFN

### heiße Teile

Mehr

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|--|--|---|---|---|
|  FDMS8025AS   |  FDMS8025S    |  FDMS8025S   |  FDMS8026S   |  FDMS8026S   |
|  FDMS8027S    |  FDMS8027S    |  FDMS8027S   |  FDMS8050    |  FDMS8050    |
|  FDMS8050ET30 |  FDMS8050ET30 |  FDMS8320L   |  FDMS8320L   |  FDMS8322    |
|  FDMS8333L    |  FDMS8333L    |  FDMS8460    |  FDMS8460    |  FDMS8460S   |
|  FDMS8558S    |  FDMS8558S    |  FDMS8558SDC |  FDMS8558SDC |  FDMS8560S   |
|  FDMS8570S    |  FDMS8570S    |  FDMS86101   |  FDMS86101   |  FDMS86101A  |
|  FDMS86101A   |  FDMS86101DC  |  FDMS86101DC |  FDMS86102LZ |  FDMS86102LZ |
|  FDMS86103L   |  FDMS86103L   |  FDMS86104   |  FDMS86104   |  FDMS86105   |
|  FDMS86105    |  FDMS86150    |  FDMS86150   |  FDMS86152   |  FDMS86152   |
|  FDMS86181    |  FDMS86181    |  FDMS86182   |  FDMS86183   |  FDMS86200   |

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